AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) An XY address type solid state image pickup device

comprising a plurality of pixels each having a photoelectric conversion unit producing a

signal from incident light arranged in rows and columns, a horizontal scanning circuit and a

vertical scanning circuit, wherein a reading operation for a signal of a pixel in one row and an

electronic shutter operation for a signal of a pixel in another row are carried out wherein the

solid state image pickup device has a plurality of signal lines, each of said signal lines being

associated with corresponding pixels and each of said signal lines is used for both said

reading operation and said shutter operation an wherein a single signal output line is used for

transferring both image output signals and output from the shutter operation for a pixel and

further wherein the image output signals and output from the shutter operation for a plurality

of pixels pass through a common transistor.

2. (Previously Presented) A solid state image pickup device according to

claim 1, characterized in that a reading operation of a signal of a pixel in one column in the

one row and an electronic shutter operation for a signal of a pixel in the one column in the

other row are performed during a same time period.

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- 3. (Previously Presented) A solid state image pickup device according to claim 1, characterized in that a reading operation of a signal of a pixel in one column in the one row and an electronic shutter operation for a signal of a pixel in a column adjacent to the one column in the other row are performed during a same time period.
- 4. (Currently Amended) A solid state image pickup device according to claim 1, eharacterize characterized in that a read scanning pulse and an electronic shutter scanning pulse are respectively supplied from said horizontal scanning circuit and said vertical scanning circuit.
- 5. (Previously Presented) A solid state image pickup device according to claim 4, characterized in that one pulse is supplied for each pixel as the read scanning pulse, one pulse is supplied for each pixel as the electronic shutter scanning pulse, and one of the read scanning pulse and the electronic shutter scanning pulse is supplied at a timing such that phases of the read scanning pulse and the electronic shutter scanning pulse do not overlap.
- 6. (Previously Presented) A solid state image pickup device according to claim 1, wherein a vertical selection switch for reading a signal charge, from the pixel in the photoelectric conversion unit, to a signal line is controlled by a product between a vertical scanning pulse and a horizontal read pulse, and further wherein a charge detection amplifier for converting the read signal charge into a voltage is connected to said signal line, and a read

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scanning pulse and an electronic shutter scanning pulse are respectively supplied from the

horizontal scanning circuit and the vertical scanning circuit.

7. (Previously Presented) A solid state image pickup device according to claim

6, characterized in that one pulse is supplied for each pixel as the read scanning pulse, one

pulse is supplied for each pixel as the electronic shutter scanning pulse, and one of the read

scanning pulse and the electronic shutter scanning pulse is supplied such that phases of the

read scanning pulse and the electronic shutter scanning pulse do not overlap.

8. (Currently Amended) A method for driving an XY address type solid state

image pickup device having an image pickup region with a plurality of pixels each having a

photoelectric conversion unit producing a signal from incident light arranged in rows and

columns, a horizontal scanning circuit, a vertical scanning circuit and a plurality of signal

lines being associated with corresponding pixels comprising:

performing a reading operation for a signal of a pixel in one row and an electronic

shutter operation for a signal of a pixel in another row and further wherein each of said signal

lines is used for both said reading operation and said shutter operation and wherein a single

signal output line is used for transferring both image output signals and output from the

shutter operation for a pixel and further wherein the image output signals and output from the

shutter operation for a plurality of pixels pass through a common transistor.

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- 9. (Previously Presented) A driving method for a solid state image pickup device according to claim 8, characterized in that a reading operation of a signal of a pixel in one column in the one row and an electronic shutter operation for a signal of a pixel in the one column in the other row are performed during a same period of time.
- 10. (Previously Presented) A driving method for a solid state image pickup device according to claim 8, characterized in that the reading operation of a pixel in one column in the one row and an electronic shutter operation for a pixel in a column adjacent to the one column in the other row are performed during a same period of time.
- 11. (Previously Presented) A driving method for a solid state image pickup device according to claim 8, characterized in that a read scanning pulse and an electronic shutter scanning pulse are respectively supplied from the horizontal scanning circuit and the vertical scanning circuit.
- 12. (Previously Presented) A driving method for a solid state image pickup device according to claim 11, characterized in that one pulse is supplied for each pixel as the read scanning pulse, one pulse is supplied for each pixel as the electronic shutter scanning pulse, and one of the read scanning pulse and the electronic shutter scanning pulse is supplied

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such that phases of the read scanning pulse and the electronic shutter scanning pulse do not overlap.

- device according to claim 8, wherein a vertical selection switch for reading a signal charge obtained by the pixel in the photoelectric conversion unit to a signal line is controlled by a product of a vertical scanning pulse and a horizontal read pulse, the signal charge read to the signal line is converted into a voltage by a charge detection amplifier connected to said signal line, and a read scanning pulse and an electronic shutter scanning pulse are respectively supplied from the horizontal scanning circuit and the vertical scanning circuit.
- 14. (Previously Presented) A driving method for a solid state image pickup device according to claim 13, characterized in that one pulse is supplied for each pixel as the read scanning pulse, one pulse is supplied for each pixel as the electronic shutter scanning pulse, and one of the read scanning pulse and the electronic shutter scanning pulse is supplied such that phases of the read scanning pulse and the electronic shutter scanning pulse do not overlap.
- 15. (Previously Presented) A camera, comprising an optical system for focusing incident light on an image pickup region of a solid state image pickup element, an XY address type solid state image pickup element having the image pickup region, a plurality of

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pixels each provided with a photoelectric conversion unit for producing a signal from the incident light arranged in rows and columns, a drive unit for driving the solid state image pickup element, and a signal processing unit for signal-processing an output signal from the solid state image pickup element to produce a video signal, wherein the drive unit has a horizontal scanning circuit and a vertical scanning circuit, and a reading operation for a signal of a pixel in one row and an electronic shutter operation for a signal of a pixel in another row are carried out by the drive unit and further wherein said solid state image pickup element has a plurality of signal lines, each of said signal lines being used for both said reading operation and said shutter operation and wherein a single signal output line is used for transferring both image output signals and output from the shutter operation for a pixel and further wherein the image output signals and output from the shutter operation for a plurality of pixels pass through a common transistor.